

Dual low voltage power amplifier



Features

- Supply voltage down to 1.8 V
- Low crossover distortion
- · Low quiescent current
- · Bridge or stereo configuration

Description

The TDA2822D is a monolithic integrated circuit in 8 lead (SO-8) package. It is intended for use as a dual audio power amplifier in portable cassette players, radios and CD players.

Product status link

TDA2822D

Ordering information

TDA2822D013TR

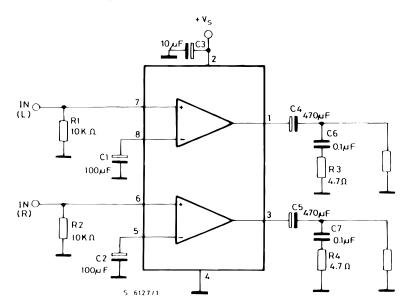


1 Application circuit

1N 0 100µF 1

Figure 1. Application circuit

Figure 2. Stereo application and test circuit



DS0119 - Rev 3 page 2/12

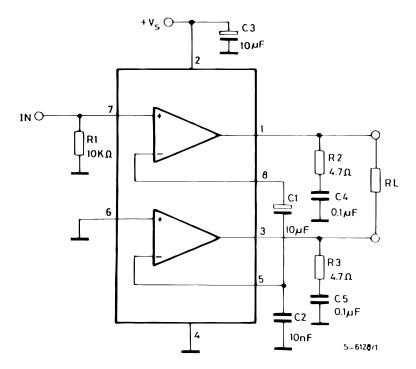


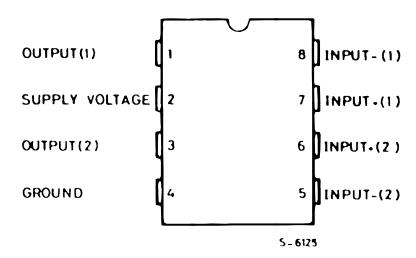
Figure 3. Bridge application and test circuit

DS0119 - Rev 3 page 3/12



2 Pin connection

Figure 4. Pin connection



DS0119 - Rev 3 page 4/12



3 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
Vs	Supply voltage	15	V
I _O	Peak output	1	Α
P _{tot}	Total power dissipation T _{amb} = 50 °C	0.5	W
T _{stg}	Storage and junction temperature	-40 to 150	°C
Tj	Storage and junction temperature	-40 to 150	C

Table 2. Thermal data

Symbol	Description		Unit
R _{thj-amb}	Thermal resistance junction-ambient max.	200	°C/W

DS0119 - Rev 3 page 5/12



4 Electrical characteristics

 $(V_S$ = 6 V; Tamb = 25 °C, unless otherwise specified. STEREO (see Figure 2. Stereo application and test circuit).

Table 3. Electrical characteristics (stereo)

Symbol	Parameter	Test o	Min.	Тур.	Max.	Unit	
V _S	Supply voltage		1.8		15	V	
I _d	Total quiescent drain current					15	mA
Vo	Quiescent output voltage				2.7		V
	V _S = 3 V		1.2		V		
I _b	Input bias current				100		nA
			V _S = 9 V		300		
			V _S = 6 V		120		mW
	Output power (each channel) (f = 1 kHz, d = 10%)	R _L = 32 Ω	V _S = 4.5 V		60		
			V _S = 3 V		20		
Po			V _S = 2 V		5		
		R _L = 16 Ω	V _S = 6 V	170	220		mW
		R _L = 8 Ω	V _S = 6 V	300	380		mW
		R _L = 4 Ω	V _S = 4.5 V		320		mW
			V _S = 3 V		110		
		R _L = 32 Ω	P _O = 40 mW		0.2		%
d	Distortion	R _L =16 Ω	P _O = 75 mW		0.2		%
		R _L = 8 Ω	P _O = 150 mW		0.2		%
G _V	Closed loop voltage gain	f = 1 kHz		36	39	41	dB
ΔG _V	Channel balance					1	dB
R _i	Input resistance	f = 1 kHz		100			kΩ
A. .	Total input noise	R_S = 10 kΩ, B = curve A			2		μV
e _N	Total Iliput Hoise	R _s = 10 kΩ, B	= 22 Hz to 22 kHz		2.5		μV
SVR	Supply voltage rejection	f = 100 Hz, C1 = C2 = 100 F		24	30		dB
Cs	Channel separation	f =	: 1 kHz		50		dB

DS0119 - Rev 3 page 6/12



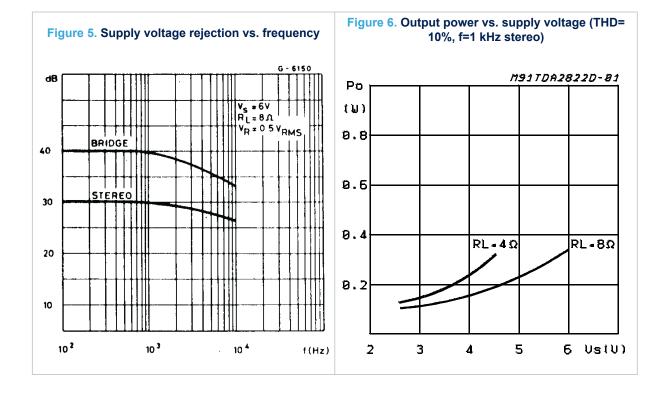
Bridge (see Figure 3. Bridge application and test circuit).

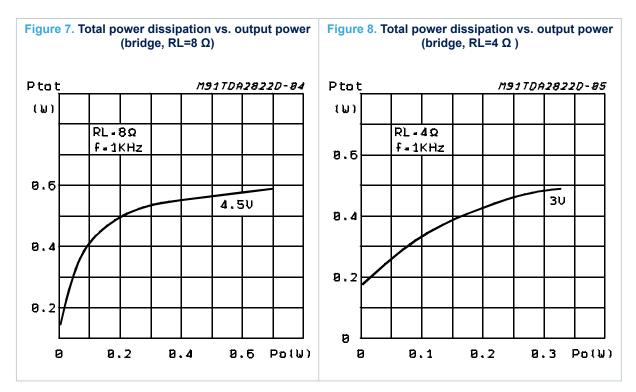
Table 4. Electrical characteristics (bridge)

Symbol	Parameter	1	Min.	Тур.	Max.	Unit	
Vs	Supply voltage		1.8		15	V	
I _d	Total quiescent drain current		R _L = ∞			15	mA
Vos	Output offset voltage between the outputs		R _L = 8 Ω			±80	mV
I _b	Input bias current				100		nA
			V _S = 9 V	1000			
			V _S = 6 V	320	400		
	Output power (f = 1 kHz, d = 10%)	R _L = 32 Ω	V _S = 4.5 V		200		mW
			V _S = 3 V	50	65		
			V _S = 2 V		8		
Po		R _L = 16 Ω	V _S = 6 V		800		mW
			V _S = 3 V		120		
		R _L = 8 Ω	V _S = 4.5 V		700		mW
			V _S = 3 V		220		
		R _L = 4 Ω	V _S = 3 V		350		mW
			V _S = 2 V		80		
d	Distortion	R _L = 8 Ω	P _O = 0.5 mW, f = 1 kHz		0.2		%
G _V	Closed loop voltage gain	f = 1 kHz			39		dB
R _i	Input resistance	f = 1 kHz		100			kΩ
		R_s =10 kΩ, B = curve A			2.5		1,5
e _N	Total input noise	R _s = 10 k	Ω, B = 22 Hz to 22 kHz		3		μV
SVR	Supply voltage rejection			40		dB	
В	Power bandwidth (-3 dB)	R _L = 8 kΩ, P _O = 1 W			120		kHz

DS0119 - Rev 3 page 7/12







DS0119 - Rev 3 page 8/12



5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

5.1 SO8 package information

Figure 9. SO8 package outline

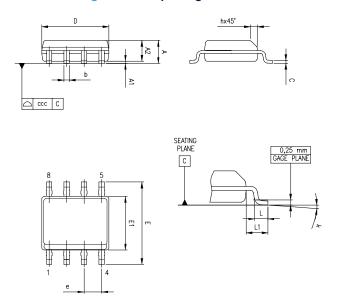


Table 5. SO-8 mechanical data

Dim	mm		Inches			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.75			0.069
A1	0.1		0.25	0.004		0.01
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
С	0.17		0.23	0.007		0.01
D	4.8	4.9	5	0.189	0.193	0.197
E	5.8	6	6.2	0.228	0.236	0.244
E1	3.8	3.9	4	0.15	0.154	0.157
е		1.27			0.05	
h	0.25		0.5	0.01		0.02
L	0.4		1.27	0.016		0.05
L1		1.04			0.04	
k			8 °			8 °
ccc			0.1			0.004

DS0119 - Rev 3 page 9/12



Revision history

Table 6. Document revision history

Date	Version	Changes	
05-Sep-2003	1	No history because of migration	
19-Sep-2016	2	No history because of migration.	
28-Aug-2020	3	Updated the ordering information table in cover page.	

DS0119 - Rev 3 page 10/12



Contents

1	Appl	ication circuit	2		
2	Pin d	connection	4		
3	Abso	olute maximum ratings	5		
4	Elec	trical characteristics	6		
5	5 Package information				
	5.1	SO-8 package information	9		
Rev		history			



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DS0119 - Rev 3 page 12/12